

# p-Type Organic Semiconductor High-purity and High-performance Pentacene



**Pentacene** (99.999%, trace metals basis)  
(purified by sublimation) [for organic electronics]  
100mg / 1g  
[P2524]

- Advantages**
- **Electronic material grade [High-purity, low metal (< 10 ppm)]**
  - **Extremely purified by sublimation**
  - **Ensures semiconductor performance by OFET devices**  
[Specification: hole mobility > 0.35 cm<sup>2</sup>/Vs (bare Si/SiO<sub>2</sub> substrate)]

## Comparison of transistor performance

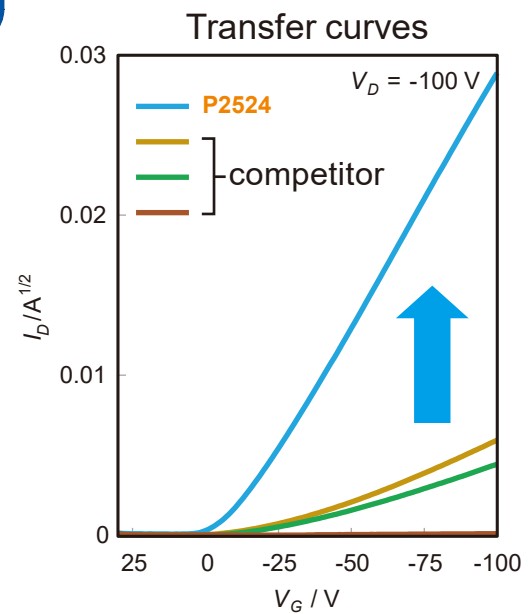
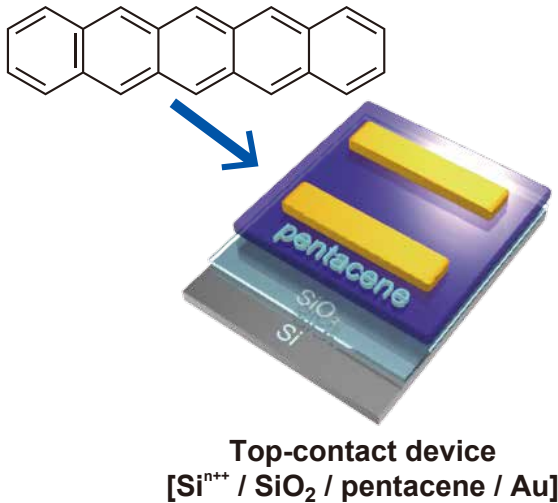


Table 1. OFET characteristics (using in-house equipment)

	Substrate	Hole Mobility (cm <sup>2</sup> /Vs)	Threshold voltage (V)
<b>P2524</b>	Si/SiO <sub>2</sub> (bare)	<b>0.39</b>	<b>-10</b>
Competitor A (sublimed)		0.002	-25
Competitor B (sublimed)		0.001	-25
Competitor C (sublimed)		$5.0 \times 10^{-6}$	-23

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## Applications

The FET performance was significantly improved by surface modification with Self-Assembled Monolayer (SAM)(OTS: *n*-octyltrichlorosilane [O0168]); the OTS-treated device with the pentacene [P2524] demonstrated very high FET performance (Figure 1 and Table 2).

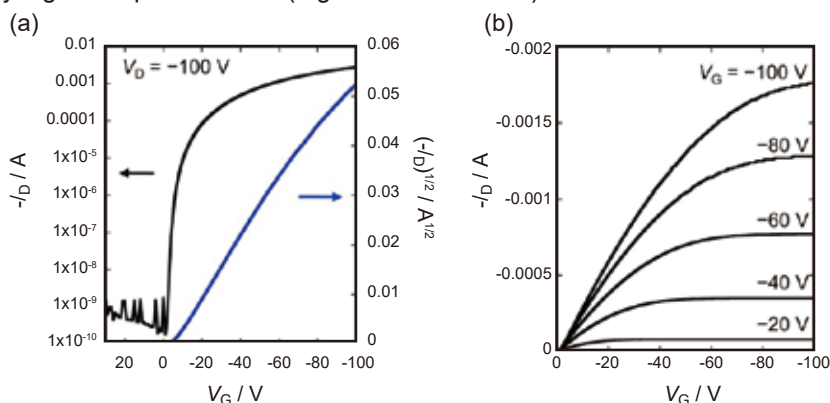


Figure 1. (a) transfer curves (b) output curves

Table 2. OFET characteristics (using in-house equipment)

	SAM	$T_{\text{sub}}$ (°C)	Hole Mobility ( $\text{cm}^2/\text{Vs}$ )	$V_{\text{TH}}$ (V)	on/off ratio
<b>Pentacene</b> [P2524]	<b>OTS</b> [O0168]	RT	1.50 - 1.52	-5.7	$1.5 \times 10^7$

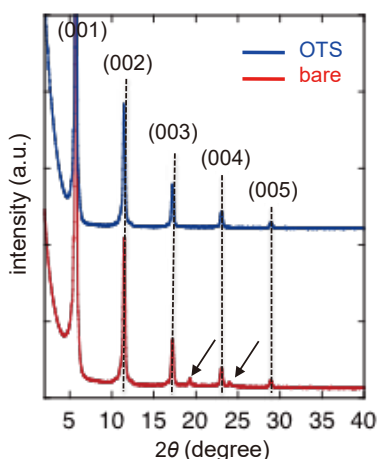


Figure 2. XRD analysis

In the bare device (without SAM), two weak peaks assignable to face-on orientation were observed (Figure 2, black arrow). This may cause a strong barrier to reduce carrier mobility (Figure 3a). On the other hand, the pentacene film on the OTS-treated substrate did not show such peaks (Figure 2). These results indicate that the OTS-treated device involves an excellent thin-film drastically enhancing the FET performance (Figure 3b).

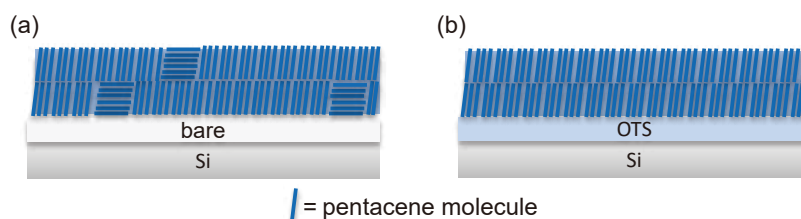


Figure 3. Orientation images of pentacene thin film form

A part of X-ray diffraction (XRD: Smart Lab) was conducted at Advanced Characterization Nanotechnology Platform of the University of Tokyo, supported by "Nanotechnology Platform" of the Ministry of Education, Culture, Sports, Science and Technology (MEXT), Japan.

## Related Product *n*-Octyltrichlorosilane (= OTS)

25g [O0168]

For further information please refer to our website at [www.TCIchemicals.com](http://www.TCIchemicals.com).

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